NSN 5962-01-381-5195

Memory Microcircuit - Page 1 of 1

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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Next assembly: a06g2795 used on: a05g0516-3
Features Provided:
Programmed and ultraviolet erasable
Inclosure Configuration:
Dual-in-line
Case Outline Source And Designator:
D-10 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.6 volts applied and 6.25 volts applied
Time Rating Per Chacteristic:
200.00 nanoseconds af output megawatts
Memory Device Type:
Eprom
Hybrid Technology Type:
Monolithic
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883
standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig: